



# 16-Bit, Ultra-Low Power, Voltage-Output Digital-to-Analog Converters

#### **FEATURES**

- Controlled Baseline
  - One Assembly
  - One Test Site
  - One Fabrication Site
- Extended Temperature Performance of -55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree (1)
- 16-Bit Resolution
- 2.7-V to 5.5-V Single-Supply Operation
- Low Power: 15 μW for 3-V Power
- High Accuracy, INL: 1 LSB
- Low Glitch: 8 nV-s
   Low Noise: 10 nV/√Hz
   Fast Settling: 1 µs
- Fast SPI Interface Up to 50 MHz
- Reset to Zero-Code
- Schmitt-Trigger Inputs for Direct Optocoupler Interface
- Industry-Standard Pin Configuration
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

#### APPLICATIONS

- Portable Equipment
- Automatic Test Equipment
- Industrial Process Control
- Data Acquisition Systems
- Optical Networking

#### **DESCRIPTION**

The DAC8830 and DAC8831 are single, 16-bit, serial-input, voltage-output digital-to-analog converters (DACs) operating from a single 3-V to 5-V power supply. These converters provide excellent linearity, low glitch, low noise, and fast settling over the specified temperature range of -55°C to 125°C. The output is unbuffered, which reduces the power consumption and the error introduced by the buffer.

These parts feature a standard high-speed (clock up to 50 MHz), 3-V or 5-V SPI serial interface to communicate with the DSP or microprocessors.

The DAC8830 output is 0 V to  $V_{REF}$ . However, the DAC8831 provides bipolar mode output ( $\pm V_{REF}$ ) when working with an external buffer. The DAC8830 and DAC8831 are both reset to zero-code after power up.

For optimum performance, a set of Kelvin connections to external reference and analog ground input are provided on the DAC8831.

The DAC8830 is available in an SO-8 package and the DAC8831 is available in an SO-14 package. Both have industry standard pinouts (see Table 3, the Cross Reference table in the *Application Information* section for details).

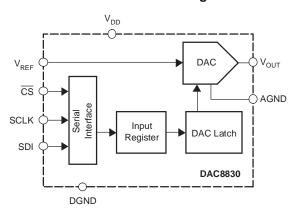


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

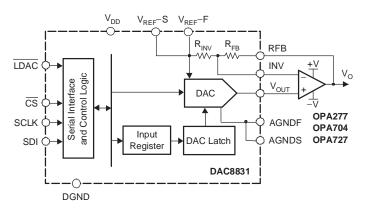
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#### DAC8830 Functional Block Diagram



#### DAC8831 Functional Block Diagram









This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because small parametric changes could cause the device not to meet its published specifications.

#### ORDERING INFORMATION(1)

PRODUCT	MINIMUM RELATIVE ACCURACY (LSB)	DIFFERENTIAL NONLINEARITY (LSB)	POWER- ON RESET VALUE	SPECIFICATION TEMPERATURE RANGE	PACKAGE MARKING	PACKAGE- LEAD	PACKAGE <sup>(2)</sup> DESIGNATOR	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
DAC8830MCD	±1	±1	Zero-Code	–55°C to 125°C	8830M	SO-8	D	DAC8830MCDREP	Tape and Reel, 2500
							_	DAC8830MCDEP	Tube, 75
DAC8831MCD	±1	±1	Zero-Code	–55°C to 125°C	8831M	SO-14	D	DAC8831MCDREP	Tape and Reel, 2500
								DAC8831MCDEP	Tube, 50

<sup>(1)</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet, or see the Texas Instruments website at www.ti.com.

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)(1)

		VALUE	UNIT
V <sub>DD</sub> to AGND		-0.3 to 7	V
Digital input voltage to DGND		-0.3 to V <sub>DD</sub> + 0.3	V
V <sub>OUT</sub> to AGND		-0.3 to V <sub>DD</sub> + 0.3	V
AGND, AGNDF, AGNDS to DGN	ID	-0.3 to 0.3	V
Operating temperature range		-55 to 125	°C
Storage temperature range		-65 to 150	°C
Junction temperature range (T <sub>J</sub> r	max)	150	°C
Power dissipation		$(T_J max - T_A)/\theta_{JA}$	W
Thermal impedance 0	SO-8	149.5	°C/W
Thermal impedance, $\theta_{JA}$	SO-14	104.5	°C/W
Load tomporature coldering	Vapor phase (60 s)	215	°C
Lead temperature, soldering	Infrared (15 s)	220	°C

<sup>(1)</sup> Stresses above those listed under absolute maximum ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.

<sup>(2)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



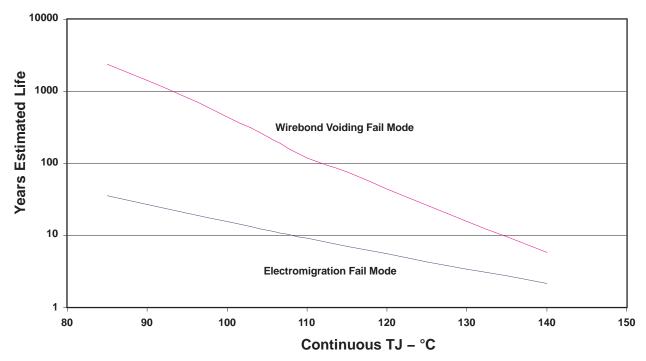


Figure 1. DAC8831MEP Operating Life Derating Chart



#### **ELECTRICAL CHARACTERISTICS**

All specifications at  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $V_{DD} = 3$  V, or  $V_{DD} = 5$  V,  $V_{REF} = 2.5$  V (unless otherwise noted); specifications subject to change without notice.

PARAM	ETER	CONDITIONS	MIN TYP	MAX	UNIT		
TATIC PERFORMANCE							
Resolution			16		bits		
		T <sub>A</sub> = 25°C	±0.5	±1			
		$T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C (DAC8831 only)}$	±0.5	±1.5			
Linearity error		$T_A = -55$ °C to 125°C (DAC8831 only)		±4	LSB		
		$T_A = -55$ °C to 125°C (DAC8830 only)	±0.5	±1.5			
Differential linearity en	or	All grades	±0.5	±1	LSB		
Coin orror		$T_A = 25^{\circ}C$	±1	±5	LSB		
Gain error		$T_A = -55^{\circ}C$ to $125^{\circ}C$		±7	LOD		
Gain drift			±0.1		ppm/°C		
		T <sub>A</sub> = 25°C	±0.25	±1	LSB		
		$T_A = -40$ °C to 105°C (DAC8831 Only)		±2.5			
Zero code error		$T_A = -55$ °C to 125°C (DAC8831 Only)		±3			
		$T_A = -55$ °C to 125°C (DAC8830 Only)		±2			
Zero code drift			±0.05		ppm/°C		
UTPUT CHARACTERISTIC	S		<u> </u>				
V 1 (1)		Unipolar operation	0	$V_{REF}$	V		
Voltage output (1)	(DAC8831 only)	Bipolar operation	-V <sub>REF</sub>	$V_{REF}$	V		
Output Impedance	1		6.25		kΩ		
Settling time		To $1/2$ LSB of FS, $C_L = 10$ pF	1		μs		
Slew rate <sup>(2)</sup>		C <sub>L</sub> = 10 pF	25		V/µs		
Digital-to-analog glitch		1 LSB change around major carry	8		nV-s		
Digital feedthrough (3)			0.2		nV-s		
	DAC8830		10		nV/√ <del>Hz</del>		
Output noise	DAC8831	T <sub>A</sub> = 25°C	18				
Power supply rejection		V <sub>DD</sub> varies ±10%		±1	LSB		
Bipolar resistor	DA C0004 1	R <sub>FB</sub> / R <sub>INV</sub>	1		Ω/Ω		
matching	DAC8831 only	Ratio error	±0.0015%	±0.01%			
D'a class	DA 00001	T <sub>A</sub> = 25°C	±0.25	±5			
Bipolar zero error	DAC8831 only	$T_A = -55^{\circ}C$ to $125^{\circ}C$		±7	LSB		
Bipolar zero drift	DAC8831 only		±0.2		ppm/°C		

<sup>(1)</sup> TheDAC8830 output is unipolar (0 V to V<sub>REF</sub>). TheDAC8831 output is bipolar (±V<sub>REF</sub>) when it connects to an external buffer (see the Bipolar Output Operation section for details).

Slew Rate is measure from 10% to 90% of transition when the output changes from 0 to full scale.

<sup>(3)</sup> Digital feedthrough is defined as the impulse injected into the analog output from the digital input. It is measured when the DAC output does not change, CS is held high, while SCLK and DIN signals are toggled.



### **ELECTRICAL CHARACTERISTICS (continued)**

All specifications at  $T_A = T_{MIN}$  to  $T_{MAX}$ ,  $V_{DD} = 3$  V, or  $V_{DD} = 5$  V,  $V_{REF} = 2.5$  V (unless otherwise noted); specifications subject to change without notice.

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT		
REF	ERENCE INPUT		-					
	Reference input voltage range <sup>(4)</sup>		1.25		$V_{DD}$	V		
	5)	Unipolar mode	9			1.0		
	Reference input impedance (5)	Bipolar mode, DAC8831	7.5			kΩ		
	Reference –3-dB bandwidth, BW	Code = FFFFh		1.3		MHz		
	Reference feedthrough	Code = 0000h, V <sub>REF</sub> = 1 V <sub>PP</sub> at 100 kHz		1		mV		
	Signal-to-noise ratio, SNR			92		dB		
	Defended in the constitution	Code = 0000h		75				
	Reference input capacitance	Code = FFFFh		120		pF		
DIGI	TAL INPUTS			<del></del>				
\	lanut lauruslinas	V <sub>DD</sub> = 2.7 V			0.6	V		
$V_{IL}$	Input low voltage	V <sub>DD</sub> = 5 V		<del></del>	0.8	V		
.,	Law of head and to me	V <sub>DD</sub> = 2.7 V	2.1	<del></del>				
$V_{IH}$	Input high voltage	V <sub>DD</sub> = 5 V	2.4			V		
	Input current				±1	μΑ		
	Input capacitance				10	pF		
	Hysteresis voltage			0.4		V		
POW	ER SUPPLY			<del></del>				
$V_{DD}$			2.7		5.5	V		
		V <sub>DD</sub> = 3 V		5	20	^		
$I_{DD}$		V <sub>DD</sub> = 5 V		5	20	μA		
	Davier	V <sub>DD</sub> = 3 V		15	60	\^/		
	Power	V <sub>DD</sub> = 5 V		25	100	μW		
TEM	PERATURE RANGE				<u>'</u>			
	Specified performance		-55		125	°C		

<sup>(4)</sup> Specified by design. V<sub>ref</sub> production tested only at 2.5 V.
(5) Reference input resistance is code dependent, minimum at 8555h.



#### PIN CONFIGURATION (NOT TO SCALE)

DAC8830ID, DAC8830IBD, DAC8830ICD (SO-8) (TOP VIEW)  $\mathrm{V}_{\mathrm{OUT}}$  $\prod V_{DD}$ DAC8830 2 AGND 7 DGND 3 6 SDI  $\mathsf{V}_{\mathsf{REF}}$ cs T 4 5 SCLK

#### DAC8831ID, DAC8831IBD, DAC8831ICD (SO-14) (TOP VIEW) RFB 🖂 14 $\square$ $V_{DD}$ 2 INV V<sub>OUT</sub> 13 DAC8831 AGNDF \_\_\_ 3 12 DGND AGNDS \_\_\_\_ 11 LDAC 5 10 SDI V<sub>REF</sub>-S 9 D NC V<sub>REF</sub>-F 6 CS □ 8 SCLK

#### **TERMINAL FUNCTIONS**

TERM	IINAL						
NO.	NAME	DESCRIPTION					
DAC8830							
1	V <sub>OUT</sub>	Analog output of DAC					
2	AGND	Analog ground					
3	$V_{REF}$	Voltage reference input					
4	CS	Chip select input (active low). Data is not clocked into SDI unless CS is low.					
5	SCLK	Serial clock input					
6	SDI	Serial data input. Data is latched into input register on the rising edge of SCLK.					
7	DGND	Digital ground					
8	VDD	Analog power supply, 3 V to 5 V					
DAC8831							
1	RFB	Feedback resistor. Connect to the output of external operational amplifier in bipolar mode.					
2	V <sub>OUT</sub>	Analog output of DAC					
3	AGNDF	Analog ground (Force)					
4	AGNDS	Analog ground (Sense)					
5	V <sub>REF-</sub> S	Voltage reference input (Sense). Connect to external voltage reference.					
6	V <sub>REF-</sub> F	Voltage reference input (Force). Connect to external voltage reference.					
7	CS	Chip select input (active low). Data is not clocked into SDI unless CS is low.					
8	SCLK	Serial clock input					
9	NC	No internal connection					
10	SDI	Serial data input. Data is latched into input register on the rising edge of SCLK.					
11	LDAC	Load DAC control input. Active low. When \overline{LDAC} is Low, the DAC latch is simultaneously updated with the content of the input register.					
12	DGND	Digital ground					
13	INV	Junction point of internal scaling resistors. Connect to external operational amplifier's inverting input in bipolar mode.					
14	VDD	Analog power supply, 3 V to 5 V					



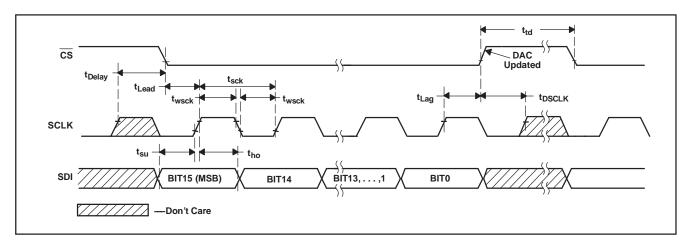


Figure 2. DAC8830 Timing Diagram

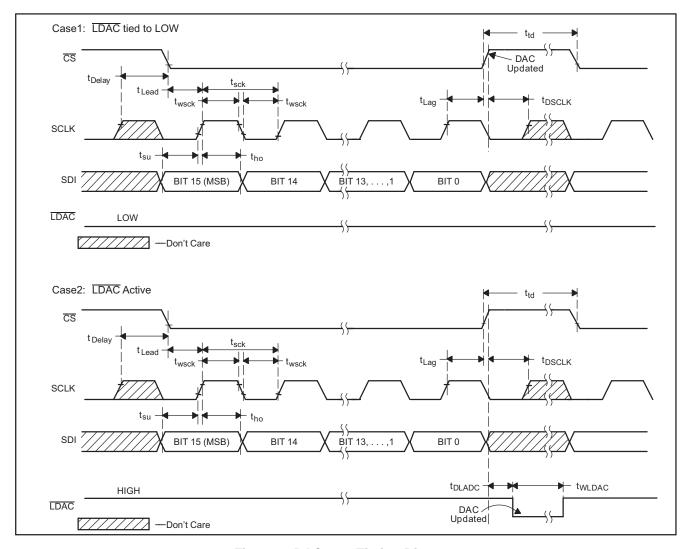


Figure 3. DAC8831 Timing Diagram



# TIMING CHARACTERISTICS: $V_{DD} = 5 V^{(1)}$ (2)

At -55°C to 125°C (unless otherwise noted)

	PARAMETER	MIN	MAX	UNIT
t <sub>sck</sub>	SCLK period	20		ns
t <sub>wsck</sub>	SCLK high or low time	10		ns
t <sub>Delay</sub>	Delay from SCLK high to CS low	18		ns
t <sub>Lead</sub>	CS enable lead time	12		ns
t <sub>Lag</sub>	CS enable lag time	15		ns
t <sub>DSCLK</sub>	Delay from CS high to SCLK high	15		ns
t <sub>td</sub>	CS high between active period	30		ns
t <sub>su</sub>	Data setup time (input)	10		ns
t <sub>ho</sub>	Data hold time (input)	0		ns
t <sub>WLDAC</sub>	LDAC width	30		ns
t <sub>DLDAC</sub>	Delay from CS high to LDAC low	30		ns
	V <sub>DD</sub> high to $\overline{\text{CS}}$ low (power-up delay)	10		μs

# TIMING CHARACTERISTICS: $V_{DD} = 3 V^{(1)}$ (2)

At -55°C to 125°C (unless otherwise noted)

	PARAMETER	MIN	MAX	UNIT
t <sub>sck</sub>	SCLK period	20		ns
t <sub>wsck</sub>	SCLK high or low time	10		ns
t <sub>Delay</sub>	Delay from SCLK high to CS low	18		ns
t <sub>Lead</sub>	CS enable lead time	15		ns
t <sub>Lag</sub>	CS enable lag time	15		ns
t <sub>DSCLK</sub>	Delay from CS high to SCLK high	15		ns
t <sub>td</sub>	CS high between active period	30		ns
t <sub>su</sub>	Data setup time (input)	10		ns
t <sub>ho</sub>	Data hold time (input)	0		ns
t <sub>WLDAC</sub>	LDAC width	30		ns
t <sub>DLDAC</sub>	Delay from CS high to LDAC low	30		ns
	V <sub>DD</sub> high to $\overline{\text{CS}}$ low (power-up delay)	10		μs

<sup>(1)</sup> Specified by design. Not production tested.

Specified by design. Not production tested. Sample tested during the initial release and after any redesign or process changes that may affect this parameter.

<sup>(2)</sup> Sample tested during the initial release and after any redesign or process changes that may affect this parameter.



#### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 5 V

At  $T_A = 25$ °C,  $V_{REF} = 2.5$  V (unless otherwise noted)

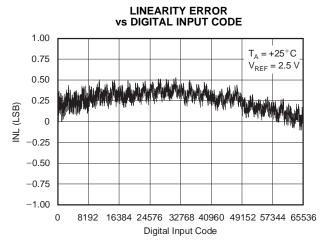


Figure 4.

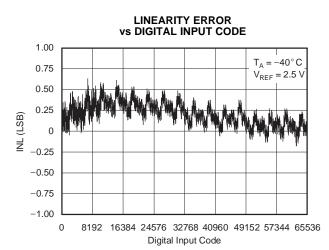


Figure 6.

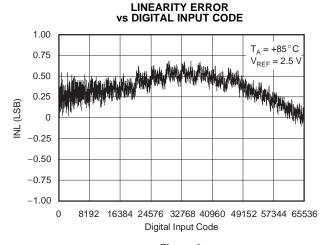


Figure 8.

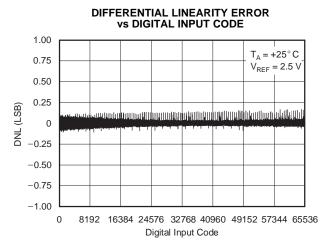
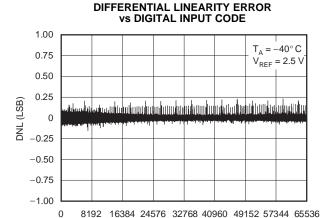


Figure 5.



0

Digital Input Code Figure 7.

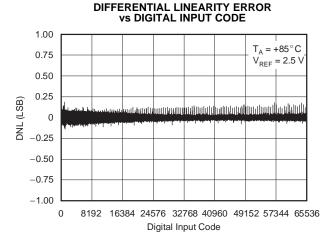


Figure 9.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 5 V (continued)

At T<sub>A</sub> = 25°C, V<sub>REF</sub> = 2.5 V (unless otherwise noted)

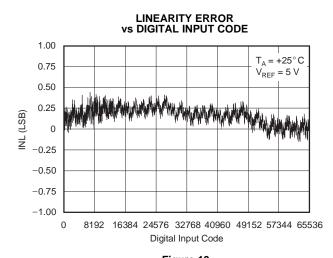


Figure 10.

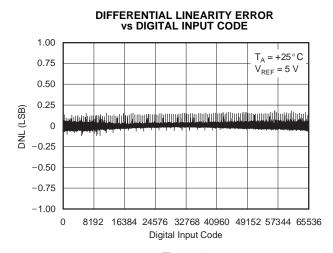


Figure 11.

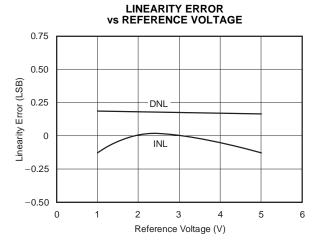


Figure 12.

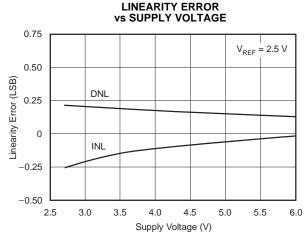


Figure 13.

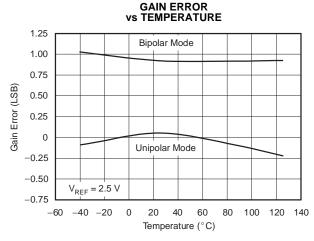


Figure 14.

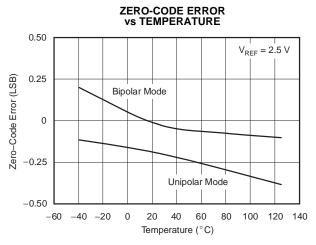


Figure 15.



### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 5 V (continued)

At  $T_A = 25^{\circ}C$ ,  $V_{REF} = 2.5 \text{ V}$  (unless otherwise noted)

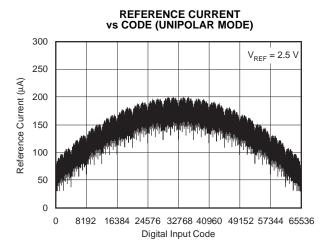


Figure 16.

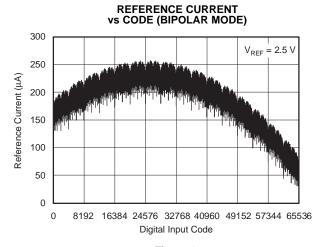


Figure 17.

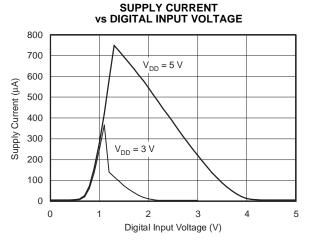


Figure 18.

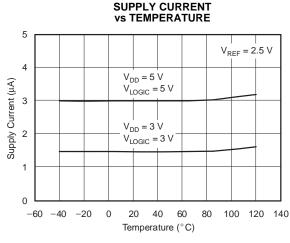


Figure 19.

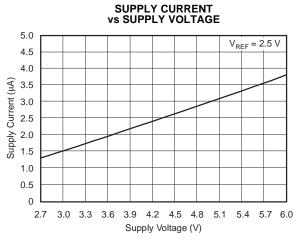


Figure 20.

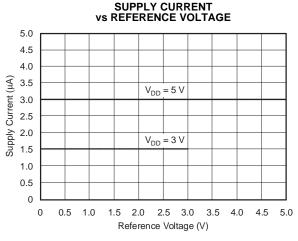


Figure 21.



# TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 5 V (continued)

At  $T_A = 25$ °C,  $V_{REF} = 2.5 \text{ V}$  (unless otherwise noted)

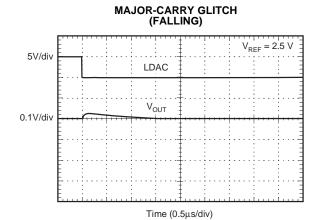


Figure 22.

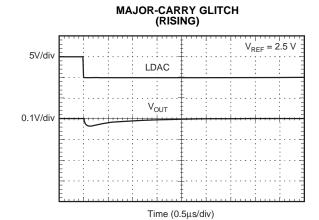


Figure 23.



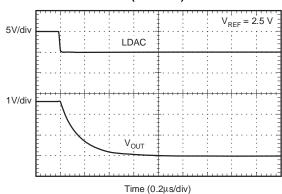


Figure 24.

# DAC SETTLING TIME (RISING)

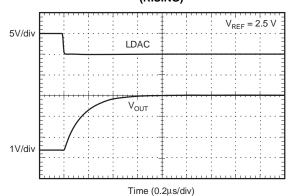


Figure 25.

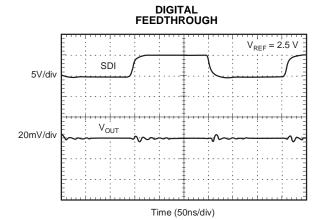


Figure 26.



#### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 3 V

At  $T_A = 25$ °C,  $V_{REF} = 2.5$  V (unless otherwise noted)

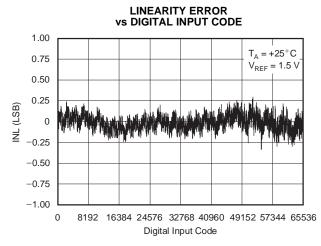


Figure 27.

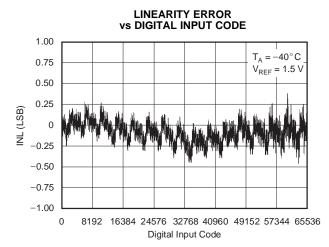


Figure 29.

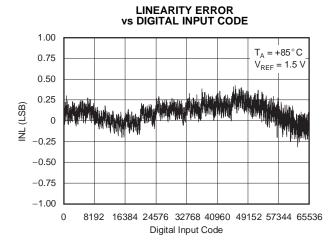


Figure 31.

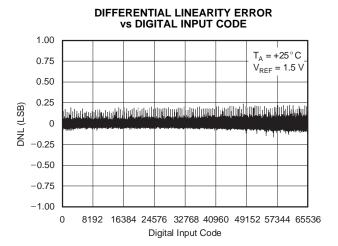
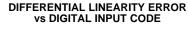


Figure 28.



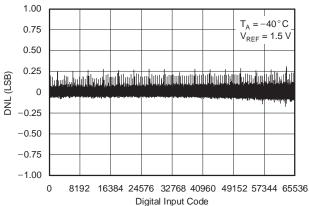


Figure 30.

# DIFFERENTIAL LINEARITY ERROR VS DIGITAL INPUT CODE

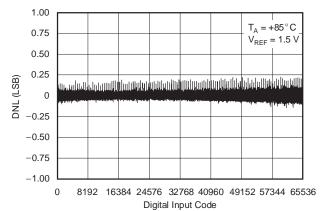


Figure 32.



#### TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 3 V (continued)

At T<sub>A</sub> = 25°C, V<sub>REF</sub> = 2.5 V (unless otherwise noted)

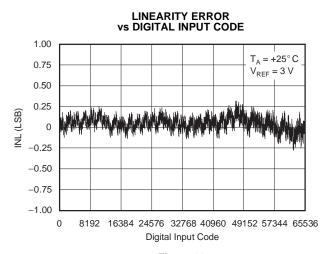


Figure 33.

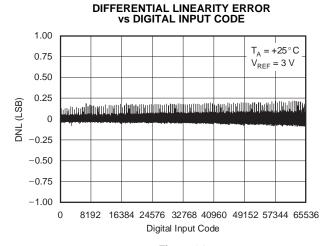


Figure 34.

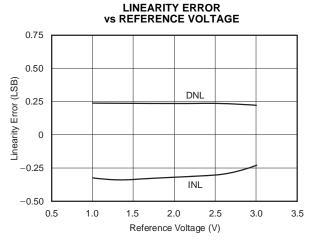


Figure 35.

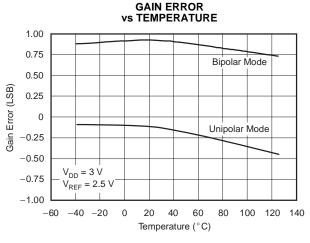


Figure 36.

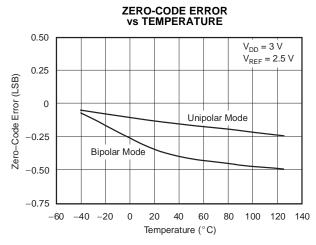


Figure 37.

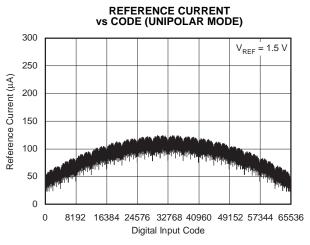


Figure 38.



# TYPICAL CHARACTERISTICS: V<sub>DD</sub> = 3 V (continued)

At  $T_A = 25^{\circ}C$ ,  $V_{REF} = 2.5 \text{ V}$  (unless otherwise noted)

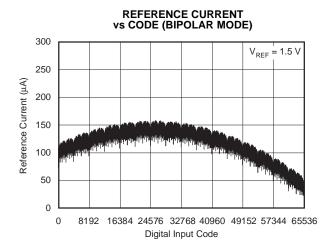


Figure 39.

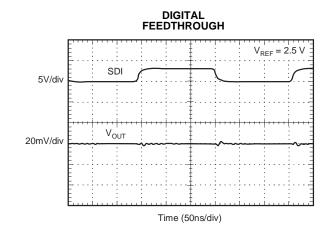


Figure 40.

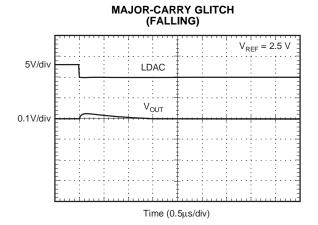


Figure 41.

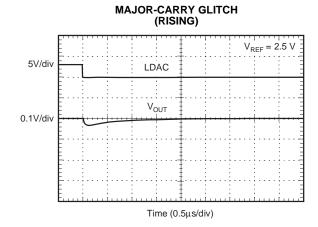


Figure 42.

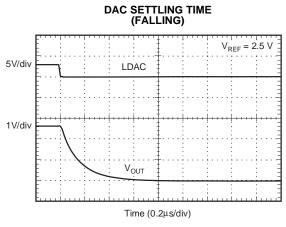


Figure 43.

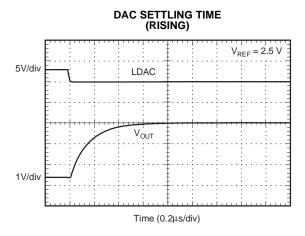


Figure 44.



#### THEORY OF OPERATION

#### **General Description**

The DAC8830 and DAC8831 are single, 16-bit, serial-input, voltage-output DACs. They operate from a single supply ranging from 2.7 V to 5 V, and typically consume 5  $\mu$ A. Data is written to these devices in a 16-bit word format, via an SPI serial interface. To ensure a known power-up state, these parts were designed with a power-on reset function. The DAC8830 and DAC8831 are reset to zero code. In unipolar mode, the DAC8830 and DAC8831 are reset to 0V, and in bipolar mode, the DAC8831 is reset to  $-V_{REF}$ . Kelvin sense connections for the reference and analog ground are included on the DAC8831.

#### **Digital-to-Analog Sections**

The DAC architecture for both devices consists of two matched DAC sections and is segmented. A simplified circuit diagram is shown in Figure 45. The four MSBs of the 16-bit data word are decoded to drive 15 switches, E1 to E15. Each of these switches connects one of 15 matched resistors to either AGND or V<sub>REF</sub>. The remaining 12 bits of the data word drive switches S0 to S11 of a 12-bit voltage mode R-2R ladder network.

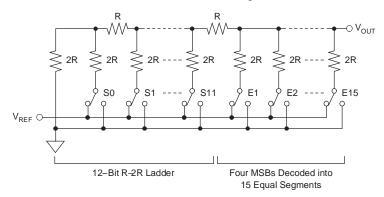


Figure 45. DAC Architecture

#### **Output Range**

The output of the DAC is

 $V_{OUT} = (V_{REF} \times Code/65536)$ 

Where:

Code = Decimal data word loaded to the DAC latch



#### **THEORY OF OPERATION (continued)**

#### **Power-on Reset**

Both devices have a power-on reset function to ensure the output is at a known state upon power up. In the DAC8830 and DAC8831, on power up, the DAC latch and input registers contain all 0s until new data is loaded from the input serial shift register. Therefore, after power up, the output from pin  $V_{OUT}$  of the DAC8830 is 0 V. The output from pin  $V_{OUT}$  of the DAC8831 is 0 V in unipolar mode and  $-V_{REF}$  in bipolar mode.

However, the serial register of the DAC8830 and DAC8831 is not cleared on power up, so its contents are undefined. When loading data initially to the device, 16 bits or more should be loaded to prevent erroneous data appearing on the output. If more than 16 bits are loaded, the last 16 are kept; if less than 16 are loaded, bits will remain from the previous word. If the device must be interfaced with data shorter than 16 bits, the data should be padded with 0s at the LSBs.

#### **Serial Interface**

The digital interface is standard 3-wire connection compatible with SPI, QSPI, Microwire, and Texas Instruments DSP interfaces, which can operate at speeds up to 50 Mbps. The data transfer is framed by  $\overline{CS}$ , the chip select signal. The DAC works as a bus slave. The bus master generates the synchronize clock, SCLK, and initiates the transmission. When  $\overline{CS}$  is high, the DAC is not accessed, and the clock SCLK and serial input data SDI are ignored. The bus master accesses the DAC by driving pin  $\overline{CS}$  low. Immediately following the high-to-low transition of  $\overline{CS}$ , the serial input data on pin SDI is shifted out from the bus master synchronously on the falling edge of SCLK, and latched on the rising edge of SCLK into the input shift register, MSB first. The low-to-high transition of  $\overline{CS}$  transfers the contents of the input shift register to the input register. All data registers are 16 bit. It takes 16 clocks of SCLK to transfer one data word to the parts. To complete a whole data word,  $\overline{CS}$  must go high immediately after 16 SCLKs are clocked in. If more than 16 SCLKs are applied during the low state of  $\overline{CS}$ , the last 16 bits are transferred to the input register on the rising edge of  $\overline{CS}$ . However, if  $\overline{CS}$  is not kept low during the entire 16 SCLK cycles, data is corrupted. In this case, reload the DAC latch with a new 16-bit word.

In the DAC8830, the contents of the input register are transferred into the DAC latch immediately when the input register is loaded, and the DAC output is updated at the same time.

The DAC8831 has an  $\overline{\text{LDAC}}$  pin allowing the DAC latch to be updated asynchronously by bringing  $\overline{\text{LDAC}}$  low after  $\overline{\text{CS}}$  goes high. In this case,  $\overline{\text{LDAC}}$  must be maintained high while  $\overline{\text{CS}}$  is low. If  $\overline{\text{LDAC}}$  is tied permanently low, the DAC latch is updated immediately after the input register is loaded (caused by the low-to-high transition of  $\overline{\text{CS}}$ ).



#### **APPLICATION INFORMATION**

#### **Unipolar Output Operation**

These DACs are capable of driving unbuffered loads of  $60~k\Omega$ . Unbuffered operation results in low supply current (typically  $5~\mu$ A) and a low offset error. The DAC8830 provides a unipolar output swing ranging from 0 V to  $V_{REF}$ . The DAC8831 can be configured to output both unipolar and bipolar voltages. Figure 46 and Figure 47 show a typical unipolar output voltage circuit for each device, respectively. The code table for this mode of operation is shown in Table 1.

Table 1. Unipolar Code

DAC Latch Contents	Analog Output				
MSB LSB	Analog Output				
1111 1111 1111 1111	V <sub>REF</sub> × (65,535/65,536)				
1000 0000 0000 0000	$V_{REF} \times (32,768/65,536) = V_{REF}$				
0000 0000 0000 0001	V <sub>REF</sub> × (1/65,536)				
0000 0000 0000 0000	0 V				

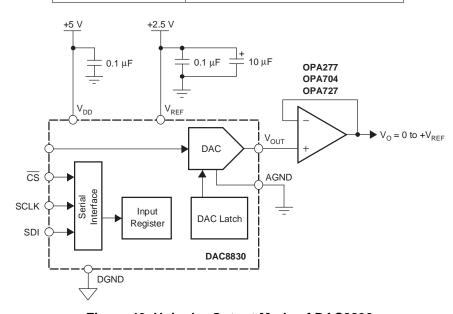


Figure 46. Unipolar Output Mode of DAC8830



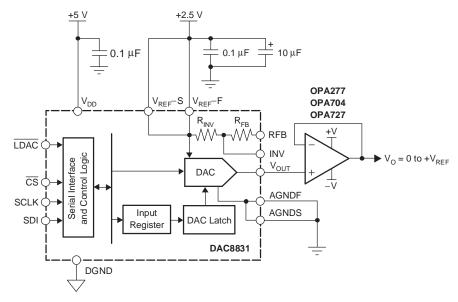


Figure 47. Unipolar Output Mode of DAC8831

Assuming a perfect reference, the worst-case output voltage may be calculated from the following equation: Unipolar Mode Worst-Case Output

$$\mathrm{V_{OUT\_UNI}} = \frac{\mathrm{D}}{\mathrm{2^{16}}} \times \left(\mathrm{V_{REF}} + \mathrm{V_{GE}}\right) + \mathrm{V_{ZSE}} + \mathrm{INL}$$

#### Where:

 $V_{OUT\_UNI}$  = Unipolar mode worst-case output

D = Code loaded to DAC

V<sub>REF</sub> = Reference voltage applied to part

V<sub>GE</sub> = Gain error in volts

 $V_{ZSE}$  = Zero scale error in volts

INL = Integral nonlinearity in volts



#### **Bipolar Output Operation**

With the aid of an external operational amplifier, the DAC8831 may be configured to provide a bipolar voltage output. A typical circuit of such an operation is shown in Figure 48. The matched bipolar offset resistors  $R_{FB}$  and  $R_{INV}$  are connected to an external operational amplifier to achieve this bipolar output swing; typically,  $R_{FB} = R_{INV} = 28 \text{ k}\Omega$ .

Table 2 shows the transfer function for this output operating mode. The DAC8831 also provides a set of Kelvin connections to the analog ground and external reference inputs.

rabio 2. Bipolai Godo							
DAC Latch Contents	Analog Output						
MSB LS	B Analog Output						
1111 1111 1111 1111	V <sub>REF</sub> × (32,767/32,768)						
1000 0000 0000 0000	V <sub>REF</sub> × (1/32,768)						
0111 1111 1111 1111	0 V						
0000 0000 0000 0001	-V <sub>REF</sub> × (1/32,768)						
0000 0000 0000 0000	$-V_{REF} \times (32,767/32,768) = -V_{REF}$						

Table 2. Bipolar Code

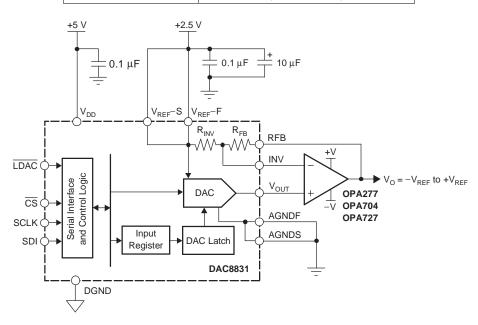


Figure 48. Bipolar Output Mode of DAC8831

Assuming a perfect reference, the worst-case output voltage may be calculated from the following equation: Bipolar Mode Worst-Case Output

$$V_{OUT\_BIP} = \frac{\left[ \left( V_{OUT\_UNI} + V_{OS} \right) (2 + RD) - V_{REF} (1 + RD) \right]}{1 + \left( \frac{2 + RD}{A} \right)}$$

#### Where:

V<sub>OS</sub> = External operational amplifier input offset voltage

 $RD = R_{FB}$  and  $R_{IN}$  resistor matching error

A = Operational amplifier open-loop gain



#### **Output Amplifier Selection**

For bipolar mode, a precision amplifier should be used, supplied from a dual power supply. This provides the  $\pm V_{REF}$  output.

In a single-supply application, selection of a suitable operational amplifier may be more difficult because the output swing of the amplifier does not usually include the negative rail; in this case, AGND. This output swing can result in some degradation of the specified performance unless the application does not use codes near 0.

The selected operational amplifier needs to have low-offset voltage (the DAC LSB is 38  $\mu$ V with a 2.5-V reference), eliminating the need for output offset trims. Input bias current should also be low because the bias current multiplied by the DAC output impedance (approximately 6.25 k $\Omega$ ) adds to the zero-code error.

Rail-to-rail input and output performance is required. For fast settling, the slew rate of the operational amplifier should not impede the settling time of the DAC. Output impedance of the DAC is constant and code-independent, but in order to minimize gain errors the input impedance of the output amplifier should be as high as possible. The amplifier should also have a 3 dB bandwidth of 1 MHz or greater. The amplifier adds another time constant to the system, thus increasing the settling time of the output. A higher 3-dB amplifier bandwidth results in a shorter effective settling time of the combined DAC and amplifier.

#### **Reference and Ground**

Since the input impedance is code-dependent, the reference pin should be driven from a low impedance source. The DAC8830 and DAC8831 operate with a voltage reference ranging from 1.25 V to  $V_{DD}$ . References below 1.25 V result in reduced accuracy.

The DAC full-scale output voltage is determined by the reference. Table 1 and Table 2 outline the analog output voltage for particular digital codes.

For optimum performance, Kelvin sense connections are provided on the DAC8831. If the application does not require separate force and sense lines, they should be tied together close to the package to minimize voltage drops between the package leads and the internal die.

#### **Power Supply and Reference Bypassing**

For accurate high-resolution performance, it is recommended that the reference and supply pins be bypassed with a 10  $\mu$ F tantalum capacitor in parallel with a 0.1  $\mu$ F ceramic capacitor.



#### **CROSS REFERENCE**

The DAC8830 and DAC8831 have an industry-standard pinout configuration (see Table 3).

**Table 3. Cross Reference** 

MODEL	INL (LSB)	DNL (LSB)	POWER-ON RESET TO	TEMPERATURE RANGE	PACKAGE DESCRIPTION	PACKAGE OPTION	CROSS REFERENCE	
DAC8830ICD	±1	±1	Zero-Code	-40°C to 85°C	8-Lead Small Outline IC	SO-8 AD55410 MAX541A		
DAC8830IBD	±2	±1	Zero-Code	-40°C to 85°C	8-Lead Small Outline IC	SO-8	AD5541BR, MAX541BESA	
DAC8830ID	±4	±1	Zero-Code	-40°C to 85°C	8-Lead Small Outline IC	SO-8	AD5541AR, MAX541CESA	
DAC8830MCD	±1	±1	Zero-Code	–55°C to 125°C	8-Lead Small Outline IC	SO-8	N/A	
N/A	±1	±1	Zero-Code	–40°C to 85°C	8-Lead Plastic DIP	PDIP-8	MAX541AEPA	
N/A	±2	±1	Zero-Code	–40°C to 85°C	8-Lead Plastic DIP	PDIP-8	MAX541BEPA	
N/A	±4	±1	Zero-Code	–40°C to 85°C	8-Lead Plastic DIP	PDIP-8	MAX541CEPA	
N/A	±1	±1	Zero-Code	0°C to 70°C	8-Lead Small Outline IC	SO-8	AD5541LR	
N/A	±2	±1.5	Zero-Code	0°C to 70°C	8-Lead Small Outline IC	SO-8	AD5541JR	
N/A	±1	±1	Zero-Code	0°C to 70°C	8-Lead Plastic DIP	PDIP-8	MAX541AEPA	
N/A	±2	±1	Zero-Code	0°C to 70°C	8-Lead Plastic DIP	PDIP-8	MAX541BEPA	
N/A	±4	±1	Zero-Code	0°C to 70°C	8-Lead Plastic DIP	PDIP-8	MAX541CEPA	
DAC8831ICD	±1	±1	Zero-Code	-40°C to 85°C	14-Lead Small Outline IC	SO-14	AD5542CR, MAX542AESD	
DAC8831IBD	±2	±1	Zero-Code	-40°C to 85°C	14-Lead Small Outline IC	SO-14	AD5542BR, MAX542BESD	
DAC8831ID	<u>±</u> 4	±1	Zero-Code	–40°C to 85°C	14-Lead Small Outline IC	SO-14	AD5542AR, MAX542CESD	
DAC8831MCD	±1	±1	Zero-Code	–55°C to 125°C	14-Lead Small Outline IC	SO-14	N/A	
N/A	±1	±1	Zero-Code	–40°C to 85°C	14-Lead Plastic DIP	PDIP-14	MAX542ACPD	
N/A	±2	±1	Zero-Code	-40°C to 85°C	14-Lead Plastic DIP	PDIP-14	MAX542BCPD	
N/A	±4	±1	Zero-Code	–40°C to 85°C	14-Lead Plastic DIP	PDIP-14	MAX542CCPD	
N/A	±4	±1	Zero-Code	–55°C to 125°C	14-Lead Ceramic SB	SB-14	MAX542CMJD	
N/A	±1	±1	Zero-Code	0°C to 70°C	14-Lead Small Outline IC	SO-14	AD5542LR	
N/A	±2	±1.5	Zero-Code	0°C to 70°C	14-Lead Small Outline IC	SO-14	AD5542JR	
N/A	±1	±1	Zero-Code	0°C to 70°C	14-Lead Small Outline IC	SO-14	SO-14 MAX542AEPD	
N/A	±2	±1	Zero-Code	0°C to 70°C	14-Lead Small Outline IC	SO-14	MAX542BEPD	
N/A	±4	±1	Zero-Code	0°C to 70°C	14-Lead Small Outline IC	SO-14	MAX542CEPD	

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
DAC8830MCDEP	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8830EP
DAC8830MCDEP.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8830EP
DAC8830MCDREP	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8830EP
DAC8830MCDREP.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8830EP
DAC8831MCDEP	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8831EP
DAC8831MCDEP.A	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8831EP
DAC8831MCDREP	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8831EP
DAC8831MCDREP.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8831EP
V62/06671-01XE	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8830EP
V62/06671-02XE	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8830EP
V62/06671-03YE	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8831EP
V62/06671-04YE	Active	Production	SOIC (D)   14	50   TUBE	Yes	NIPDAU	Level-3-260C-168 HR	-55 to 125	8831EP

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

### **PACKAGE OPTION ADDENDUM**

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#### OTHER QUALIFIED VERSIONS OF DAC8830-EP, DAC8831-EP:

Catalog: DAC8830, DAC8831

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

# **PACKAGE MATERIALS INFORMATION**

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#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC8830MCDREP	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
DAC8831MCDREP	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC8830MCDREP	SOIC	D	8	2500	350.0	350.0	43.0
DAC8831MCDREP	SOIC	D	14	2500	350.0	350.0	43.0

# **PACKAGE MATERIALS INFORMATION**

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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
DAC8830MCDEP	D	SOIC	8	75	505.46	6.76	3810	4
DAC8830MCDEP.A	D	SOIC	8	75	505.46	6.76	3810	4
DAC8831MCDEP	D	SOIC	14	50	505.46	6.76	3810	4
DAC8831MCDEP.A	D	SOIC	14	50	505.46	6.76	3810	4
V62/06671-02XE	D	SOIC	8	75	505.46	6.76	3810	4
V62/06671-04YE	D	SOIC	14	50	505.46	6.76	3810	4





#### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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